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# VS-MURB2020CTHM3, VS-MURB2020CT-1HM3

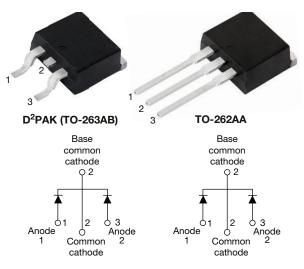
**Vishay Semiconductors** 

RoHS

COMPLIANT HALOGEN

FREE

# Ultrafast Rectifier, 2 x 10 A FRED Pt®



## LINKS TO ADDITIONAL RESOURCES



PRIMARY CHARACTERISTICS								
I <sub>F(AV)</sub>	2 x 10 A							
V <sub>R</sub>	200 V							
V <sub>F</sub> at I <sub>F</sub>	0.85							
t <sub>rr</sub> typ.	19 ns							
T <sub>J</sub> max.	175 °C							
Package	D <sup>2</sup> PAK (TO-263AB), TO-262AA							
Circuit configuration	Common cathode							

## FEATURES

- Ultrafast recovery time
- Low forward voltage drop
- Low leakage current
- 175 °C operating junction temperature
- Meets MSL level 1, per J-STD-020, LF maximum peak of 260 °C
- AEC-Q101 qualified
- Meets JESD 201 class 1 whisker test
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

## **DESCRIPTION / APPLICATIONS**

MUR.. series are the state of the art ultrafast recovery rectifiers specifically designed with optimized performance of forward voltage drop and ultrafast recovery time.

The planar structure and the platinum doped life time control, guarantee the best overall performance, ruggedness and reliability characteristics.

These devices are intended for use in the output rectification stage of SMPS, UPS, DC/DC converters as well as freewheeling diode in low voltage inverters and chopper motor drives.

Their extremely optimized stored charge and low recovery current minimize the switching losses and reduce over dissipation in the switching element and snubbers.

## **MECHANICAL DATA**

Case: D<sup>2</sup>PAK (TO-263AB), TO-262AA Molding compound meets UL 94 V-0 flammability rating

Terminals: matte tin plated leads, solderable per J-STD-002

ABSOLUTE MAXIMUM RATINGS										
PARAMETER		SYMBOL	TEST CONDITIONS	MAX.	UNITS					
Peak repetitive reverse voltage		V <sub>RRM</sub>		200	V					
Average rectified forward current	per leg	1		10						
Average rectilied forward current	total device	I <sub>F(AV)</sub>	Rated V <sub>R</sub> , T <sub>C</sub> = 145 °C	20	^					
Non-repetitive peak surge current per leg		I <sub>FSM</sub>		100	A					
Peak repetitive forward current per leg		I <sub>FM</sub>	Rated V <sub>R</sub> , square wave, 20 kHz, T <sub>C</sub> = 145 $^{\circ}$ C	20						
Operating junction and storage tem	peratures	T <sub>J</sub> , T <sub>Stg</sub>		-65 to +175	°C					

<b>ELECTRICAL SPECIFICATIONS</b> (T <sub>J</sub> = 25 $^{\circ}$ C unless otherwise specified)										
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS				
Breakdown voltage, blocking voltage	$V_{BR}, V_{R}$	I <sub>R</sub> = 100 μA	200	-	-					
Forward voltage		I <sub>F</sub> = 8 A, T <sub>J</sub> = 125 °C	-	-	0.85	v				
	V <sub>F</sub>	I <sub>F</sub> = 16 A	-	-	1.15	v				
		I <sub>F</sub> = 16 A, T <sub>J</sub> = 125 °C	-	-	1.05					
Reverse leakage current		$V_R = V_R$ rated	-	-	15					
Reverse leakage current	IR	$T_J = 150 \text{ °C}, V_R = V_R \text{ rated}$	-	-	250	μA				
Junction capacitance	CT	V <sub>R</sub> = 200 V	-	55	-	pF				
Series inductance	L <sub>S</sub>	Measured lead to lead 5 mm from package body	-	8.0	-	nH				

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<b>DYNAMIC RECOVERY CHARACTERISTICS</b> (T <sub>J</sub> = 25 $^{\circ}$ C unless otherwise specified)										
PARAMETER	SYMBOL	TEST CO	NDITIONS	MIN.	TYP.	MAX.	UNITS			
Reverse recovery time		$I_F = 1.0 \text{ A}, \text{ d}I_F/\text{d}t =$	100 A/ $\mu$ s, V <sub>R</sub> = 30 V	-	19	-				
	t <sub>rr</sub>	T <sub>J</sub> = 25 °C		-	21	-	ns A			
		T <sub>J</sub> = 125 °C		-	35	-				
Poak rocovory ourront	I <sub>RRM</sub>	T <sub>J</sub> = 25 °C	I <sub>F</sub> = 10 A dI <sub>F</sub> /dt = 200 A/μs	-	1.9	-				
Peak recovery current		T <sub>J</sub> = 125 °C	$V_{\rm B} = 160 \text{ V}$	-	4.8	-	~			
	0	T <sub>J</sub> = 25 °C	] • • • • • • • •	-	25	-	nC			
Reverse recovery charge	Q <sub>rr</sub>	T <sub>J</sub> = 125 °C		-	78	-				

THERMAL - MECHANICAL SPECIFICATIONS										
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS				
Maximum junction and storage temperature range	T <sub>J</sub> , T <sub>Stg</sub>		-65	-	175	°C				
Thermal resistance, junction to case per leg	R <sub>thJC</sub>		-	-	2.5					
Thermal resistance, junction to ambient per leg	R <sub>thJA</sub>		-	-	50	°C/W				
Thermal resistance, case to heatsink	R <sub>thCS</sub>	Mounting surface, flat, smooth and greased	-	0.5	-					
Weight			-	2.0	-	g				
Mounting torque			6.0 (5.0)	-	12 (10)	kgf · cm (lbf · in)				
Marking davias		Case style D <sup>2</sup> PAK (TO-263AB)	MURB2020CTH							
Marking device		Case style TO-262		MURB20	20CT-1H					

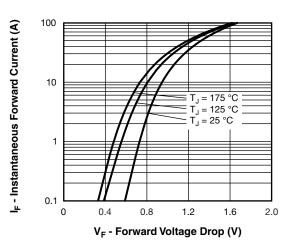


Fig. 1 - Typical Forward Voltage Drop Characteristics

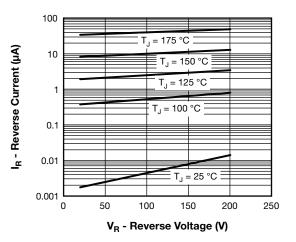


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage

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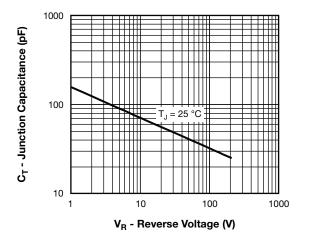


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

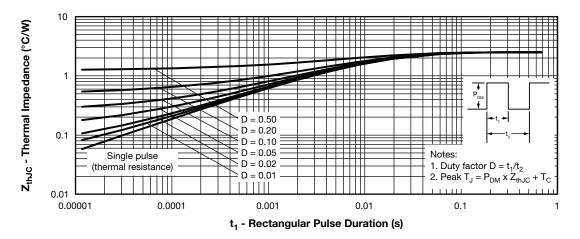
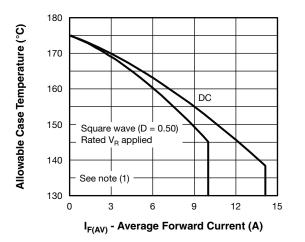
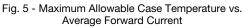


Fig. 4 - Maximum Thermal Impedance Z<sub>thJC</sub> Characteristics





### Note

<sup>(1)</sup> Formula used:  $T_C = T_J - (Pd + Pd_{REV}) \times R_{thJC}$ ;

 $\begin{array}{l} \mbox{Pd} = \mbox{Forward power loss} = \mbox{I}_{F(AV)} \times \mbox{V}_{FM} \mbox{ at } (\mbox{I}_{F(AV)}/D) \mbox{ (see fig. 6);} \\ \mbox{Pd}_{REV} = \mbox{Inverse power loss} = \mbox{V}_{R1} \times \mbox{I}_{R} \mbox{ (1 - D); I}_{R} \mbox{ at } \mbox{V}_{R1} = \mbox{Rated } \mbox{V}_{R} \end{array}$ 

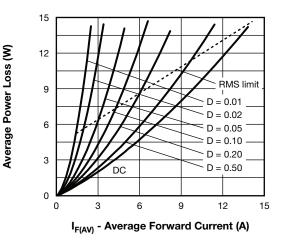


Fig. 6 - Forward Power Loss Characteristics

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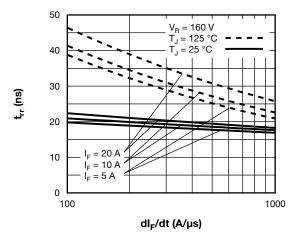


Fig. 7 - Typical Reverse Recovery Time vs. dl<sub>F</sub>/dt

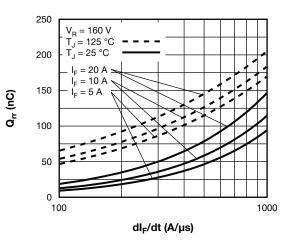


Fig. 8 - Typical Stored Charge vs. dl<sub>F</sub>/dt

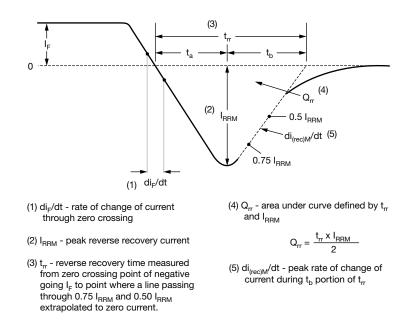


Fig. 9 - Reverse Recovery Waveform and Definitions

ORDERING INFORMATION (Example)										
PREFERRED P/N	QUANTITY PER TUBE	MINIMUM ORDER QUANTITY	PACKAGING DESCRIPTION							
VS-MURB2020CTHM3	50	1000	Antistatic plastic tube							
VS-MURB2020CT-1HM3	50	1000	Antistatic plastic tube							
VS-MURB2020CTLHM3	800	800	13" diameter reel							
VS-MURB2020CTRHM3	800	800	13" diameter reel							

LINKS TO RELATED DOCUMENTS		
Dimensions	TO-263AB (D <sup>2</sup> PAK)	www.vishay.com/doc?95046
Dimensions	TO-262AA	www.vishay.com/doc?95419
Part marking information	TO-263AB (D <sup>2</sup> PAK)	www.vishay.com/doc?95444
Fait marking information	TO-262AA	www.vishay.com/doc?95443
Packaging information	TO-263AB (D <sup>2</sup> PAK)	www.vishay.com/doc?95032
SPICE model		www.vishay.com/doc?96995

# VS-MURB2020CTHM3, VS-MURB2020CT-1HM3

## Vishay Semiconductors

## **ORDERING INFORMATION TABLE**

Device code	vs-	MUR	в	20	20	ст	-1	L	н	М3
(	(1)	(2)	(3)	4	(5)	6	(7)	(8)	(9)	(10)
1	1.	Vish	av Sem	niconduo	ctors pro	oduct				
	2 - Ultrafast MUR series									
	<b>3</b> - $B = D^2 PAK/TO-262$									
4		Curi	ent rati	ng (20 =	= 20 A)					
5	_	Volt	age rati	ng (20 =	= 200 V)					
6		CT :	= Cente	r tap (dı	ual) TO-	220/D <sup>2</sup> I	PAK/TC	)-262		
7	- [	• -1	= TO-2	62						
		• No	one = D <sup>2</sup>	<sup>2</sup> PAK						
8	- 1	• No	one							
	<ul> <li>L = Tape and reel (left oriented, for D<sup>2</sup>PAK package)</li> </ul>									
	<ul> <li>R = Tape and reel (right oriented, for D<sup>2</sup>PAK package)</li> </ul>									
9	9 - H = AEC-Q101 qualified									
10	) -	M3 :	= Halog	en-free,	RoHS-	complia	nt, and	termina	tions lea	ad (Pb)-



# **Outline Dimensions**



D<sup>2</sup>PAK

### **DIMENSIONS** in millimeters and inches

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SYMBOL	MILLIM	IETERS	INC	HES	NOTES	SYMBOL	MILLIM	IETERS	INC	HES	NOTES	
STMBOL	MIN.	MAX.	MIN.	MAX.		STWDUL	MIN.	MAX.	MIN.	MAX.	NOTES	
A	4.06	4.83	0.160	0.190			D1	6.86	8.00	0.270	0.315	3
A1	0.00	0.254	0.000	0.010			E	9.65	10.67	0.380	0.420	2, 3
b	0.51	0.99	0.020	0.039			E1	7.90	8.80	0.311	0.346	3
b1	0.51	0.89	0.020	0.035	4		е	2.54	BSC	0.100	BSC	
b2	1.14	1.78	0.045	0.070			Н	14.61	15.88	0.575	0.625	
b3	1.14	1.73	0.045	0.068	4		L	1.78	2.79	0.070	0.110	
С	0.38	0.74	0.015	0.029			L1	-	1.65	-	0.066	3
c1	0.38	0.58	0.015	0.023	4		L2	1.27	1.78	0.050	0.070	
c2	1.14	1.65	0.045	0.065			L3	0.25	BSC	0.010	BSC	
D	8.51	9.65	0.335	0.380	2		L4	4.78	5.28	0.188	0.208	

#### Notes

<sup>(1)</sup> Dimensioning and tolerancing per ASME Y14.5 M-1994

<sup>(2)</sup> Dimension D and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outmost extremes of the plastic body

<sup>(3)</sup> Thermal pad contour optional within dimension E, L1, D1 and E1

<sup>(4)</sup> Dimension b1 and c1 apply to base metal only

<sup>(5)</sup> Datum A and B to be determined at datum plane H

<sup>(6)</sup> Controlling dimension: inch

<sup>(7)</sup> Outline conforms to JEDEC<sup>®</sup> outline TO-263AB

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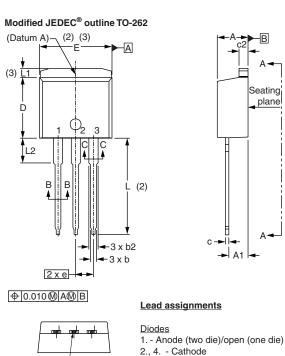
## **Outline Dimensions**



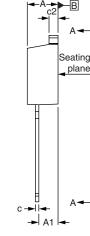
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**TO-262** 

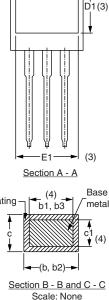
### **DIMENSIONS** in millimeters and inches



Lead tip -



E1 Plating



Е

MILLIMETERS INCHES SYMBOL NOTES MIN. MAX. MIN. MAX. А 4.06 4.83 0.160 0.190 2.03 A1 3.02 0.080 0.119 b 0.51 0.99 0.020 0.039 b1 0.51 0.89 0.020 0.035 4 b2 1.14 1.78 0.045 0.070 1.14 1.73 0.045 0.068 4 b3 0.38 0.74 0.015 0.029 С 0.38 0.58 0.015 0.023 4 c1 1.14 1.65 0.045 0.065 c2 D 8.51 9.65 0.335 0.380 2 D1 6.86 8.00 0.270 0.315 3 Е 9.65 10.67 0.380 0.420 2, 3 E1 7.90 8.80 0.311 0.346 3 0.100 BSC 2.54 BSC е L 13.46 14.10 0.530 0.555 L1 \_ 1.65 0.065 3 \_ 3.36 0.132 0.146 L2 3.71

3. - Anode

### Notes

<sup>(1)</sup> Dimensioning and tolerancing as per ASME Y14.5M-1994

<sup>(4)</sup> Dimension b1 and c1 apply to base metal only

(5) Controlling dimension: inches

<sup>(2)</sup> Dimension D and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outmost extremes of the plastic body

<sup>(3)</sup> Thermal pad contour optional within dimension E, L1, D1 and E1

Outline conform to JEDEC TO-262 except A1 (maximum), (6) b (minimum), D1 (minimum) and L2 where dimensions derived the actual package outline

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